### **VS-20CUT10, VS-20CWT10FN**

Vishay Semiconductors

RoHS COMPLIANT

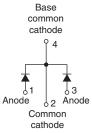
# High Performance Schottky Generation 5.0, 2 x 10 A

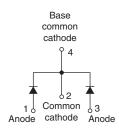




I-PAK (TO-251AA)

D-PAK(TO-252AA)





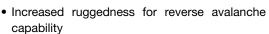
VS-20CUT10

VS-20CWT10FN

PRODUCT SUMMARY					
Package	D-PAK (TO-252AA), I-PAK (TO-251AA)				
I <sub>F(AV)</sub>	2 x 10 A				
$V_{R}$	100 V				
V <sub>F</sub> at I <sub>F</sub>	0.66 V				
I <sub>RM</sub> max.	4 mA at 125 °C				
T <sub>J</sub> max.	175 °C				
Diode variation	Common cathode				
E <sub>AS</sub>	54 mJ				

#### **FEATURES**

- 175 °C high performance Schottky diode
- · Very low forward voltage drop
- Extremely low reverse leakage
- Optimized V<sub>F</sub> vs. I<sub>R</sub> trade off for high efficiency



- RBSOA available
- Negligible switching losses
- Submicron trench technology
- Compliant to RoHS Directive 2002/95/EC

#### **APPLICATIONS**

- High efficiency SMPS
- High frequency switching
- Output rectification
- Reverse battery protection
- Freewheeling
- DC/DC systems
- Increased power density systems

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS VALUES UNITS					
V <sub>RRM</sub>		100	V			
V <sub>F</sub>	10 Apk, T <sub>J</sub> = 125 °C (typical, per leg)	0.615	V			
T <sub>J</sub>	Range	- 55 to 175	°C			

VOLTAGE RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VS-20CUT10 VS-20CWT10FN	UNITS
Maximum DC reverse voltage	$V_{R}$	T <sub>J</sub> = 25 °C	100	V



# **VS-20CUT10, VS-20CWT10FN**

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ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	L TEST CONDITIONS		VALUES	UNITS
Maximum average	per leg		50 % duty cycle at T <sub>C</sub> = 159 °C, rectangular waveform		10	Α
forward current	per device	- I <sub>F(AV)</sub>			20	
Maximum peak one cyc	vole		Following any rated load condition and with rated	610	Α	
non-repetitive surge current per leg		I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	110	A
Non-repetitive avalanch energy per leg	ne	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 3 A, L = 12 mH		54	mJ
Repetitive avalanche cu	urrent per leg	I <sub>AR</sub>	Limited by frequency of operation and time pulse duration so that $T_J < T_J max$ . $I_{AS}$ at $T_J max$ . as a function of time pulse (see fig. 8)		I <sub>AS</sub> at T <sub>J</sub> max.	А

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
Forward voltage drop per leg	V <sub>FM</sub> <sup>(1)</sup>	10 A	T <sub>J</sub> = 25 °C	0.735	0.810	V
		20 A		0.840	0.890	
		10 A	T <sub>J</sub> = 125 °C	0.615	0.660	
		20 A		0.730	0.770	
Reverse leakage current per leg	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	V <sub>R</sub> = Rated V <sub>R</sub>	-	50	μA
		T <sub>J</sub> = 125 °C		-	4	mA
Junction capacitance per leg	C <sub>T</sub>	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		400	-	pF
Series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 mm from package body		8.0	-	nΗ
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		-	10 000	V/µs

### Note

 $<sup>^{(1)}\,</sup>$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 55 to 175	°C
Maximum thermal resistance, junction to case per leg				
Maximum thermal resistance, junction to case per device	- R <sub>thJC</sub>	DC operation	1	°C/W
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>		0.3	
Approximate weight			0.3	g
			0.01	OZ.
Madina		Case style I-PAK		JT10
Marking device		Case style D-PAK	20CW	T10FN

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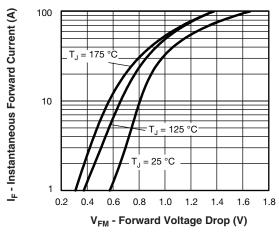


Fig. 1 - Maximum Forward Voltage Drop Characteristics

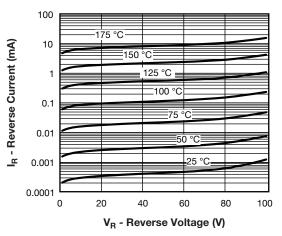


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

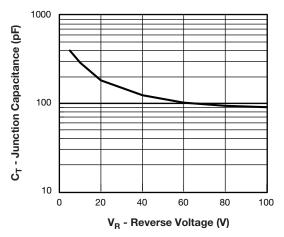


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

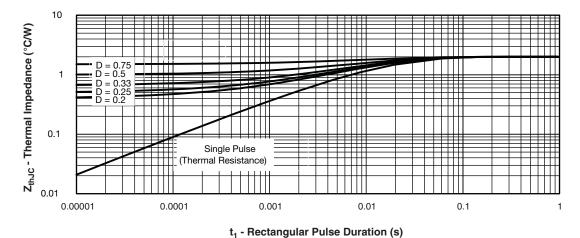


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

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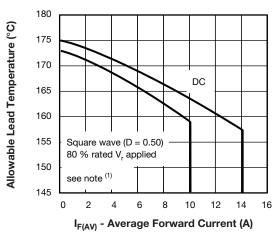


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

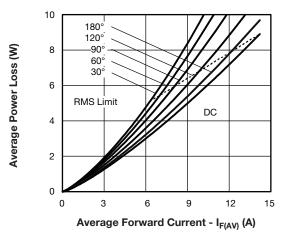


Fig. 6 - Forward Power Loss Characteristics

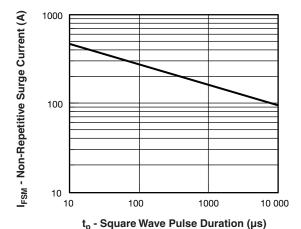


Fig. 7 - Maximum Non-Repetitive Surge Current

#### Note

Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ; Pd = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6); Pd<sub>REV</sub> = Inverse power loss =  $V_{R1} \times I_R$  (1 - D);  $I_R$  at  $V_{R1}$  = 80 % rated  $V_R$ 

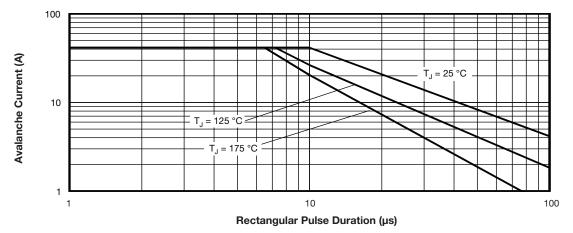


Fig. 8 - Reverse Bias Safe Operating Area (Avalanche Current vs. Rectangular Pulse Duration)

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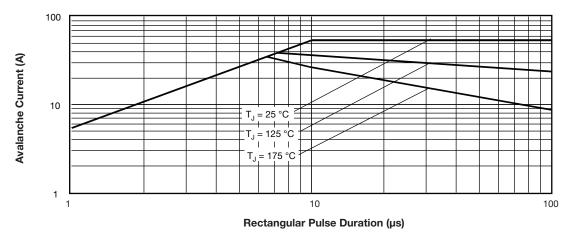
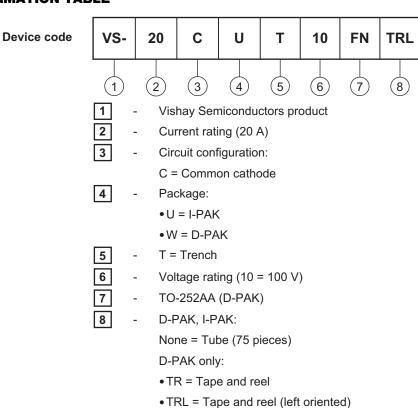


Fig. 9 - Reverse Bias Safe Operating Area (Avalanche Energy vs. Rectangular Pulse Duration)

#### **ORDERING INFORMATION TABLE**



LINKS TO RELATED DOCUMENTS					
Dimensions	I-PAK (TO-251AA)	www.vishay.com/doc?95024			
Differsions	D-PAK (TO-252AA)	www.vishay.com/doc?95448			
Part marking information	I-PAK (TO-251AA)	www.vishay.com/doc?95025			
	D-PAK (TO-252AA)	www.vishay.com/doc?95059			
Packaging information		www.vishay.com/doc?95033			
SPICE model		www.vishay.com/doc?95041			

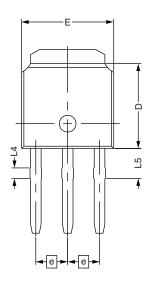
• TRR = Tape and reel (right oriented)

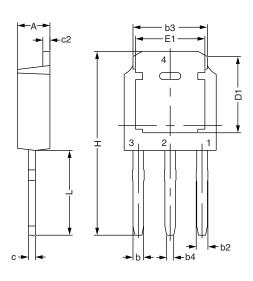


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### I-PAK - S

### **DIMENSIONS FOR I-PAK - S** in millimeters





SYMBOL	DIMENSIONAL REQUIREMENTS				
STWIBOL	MIN.	NOM.	MAX.		
E	6.40	6.60	6.70		
L	3.98	4.13	4.28		
L4	0.66	0.76	0.86		
L5	1.96	2.16	2.36		
D	6.00	6.10	6.20		
Н	11.05	11.25	11.45		
b	0.64	0.76	0.88		
b2	0.77	0.84	1.14		
b3	5.21	5.34	5.46		
b4	0.41	0.51	0.61		
е	2.286 BSC				
Α	2.20	2.20 2.30			
С	0.40	0.40 0.50			
c2	0.40	0.40 0.50 0.			
D1	5.30		-		
E1	4.40	-	-		



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